PNP/NPN Epitaxial Planar Silicon Darlington Transistor



2SB1225/2SD1827

Driver Applications

Applications

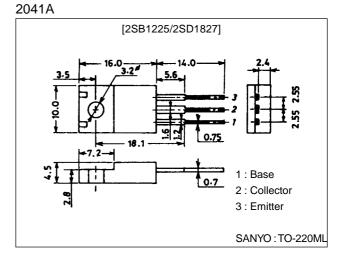
• Suitable for use in cotrol of motor drivers, printer hammer drivers, relay drivers, and constant-voltage regulators.

Features

- · High DC current gain.
- · Large current capacity and wide ASO.
- · Low saturation voltage.
- · Micaless package facilitating mounting.

Package Dimensions

unit:mm



():2SB1225

Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		(–)70	V
Collector-to-Emitter Voltage	VCEO		(–)60	V
Emitter-to-Base Voltage	VEBO		(–)6	V
Collector Current	ι _C		(–)10	A
Collector Current (Pulse)	ICP		(–)15	A
Collector Dissipation	PC		2.0	W
		Tc=25°C	30	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta = 25°C

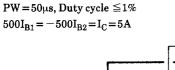
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	ICBO	V _{CB} =(-)40V, I _E =0			(–)0.1	mA
Emitter Cutoff Current	IEBO	V _{EB} =(-)5V, I _C =0			(–)3.0	mA
DC Current Gain	hFE	V _{CE} =(-)2V, I _C =(-)5A	2000	5000		
Gain-Bandwidth Product	fT	V _{CE} =(-)5V, I _C =(-)5A		20		MHz
Collector-to-Emitter Saturation Voltage	V _{CE(sat)}	I _C =(-)5A, I _B =(-)10mA		0.9	(–)1.5	V
				(–1.0)		V
Base-to-Emitter Saturation Voltage	V _{BE(sat)}	I _C =(-)5A, I _B =(-)10mA			(–)2.0	V

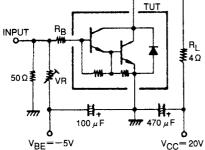
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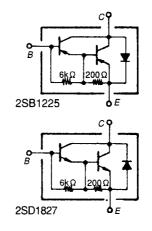
Parameter	Symbol	Conditions		Ratings		
			min	typ	max	Unit
Collector-to-Base Breakdown Voltage	V _(BR) CBO	I _C =(-)5mA, I _E =0	(–)70			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	I _C =(−)50mA, R _{BE} =∞	(–)60			V
Turn-ON TIme	ton	See specified Test Circuit		0.6		μs
				(0.5)		μs
Storage Time	t _{stg}	See specified Test Circuit		3.0		μs
				(1.5)		μs
Fall Time	t _f	See specified Test Circuit		1.8		μs
				(1.7)		μs

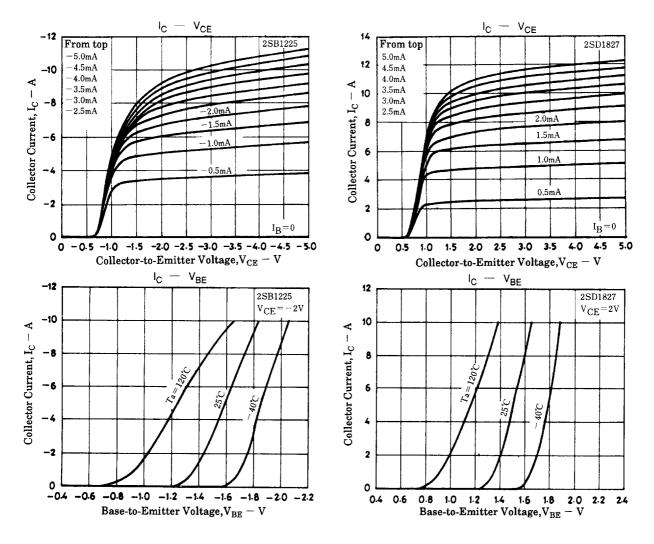
Switching Time Test Circuit





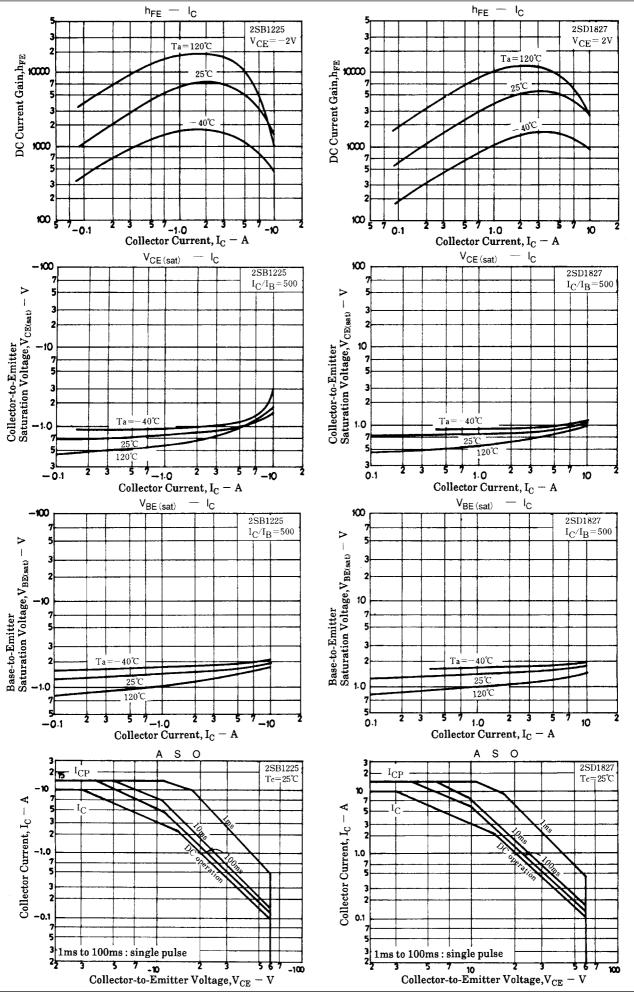
(For PNP, the polarity is reversed.)



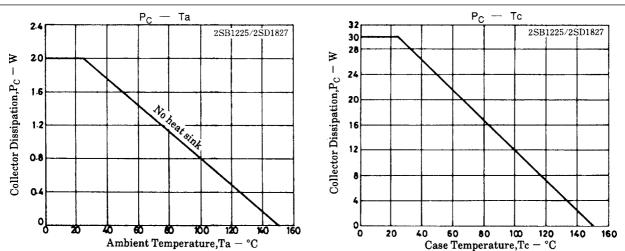


Electrical Connection

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No.2211-3/4



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